

BILKENT UNIVERSITY  
Department of Electrical and Electronics Engineering  
EEE102 Introduction to Digital Circuit Design  
MidTerm Exam I SOLUTION

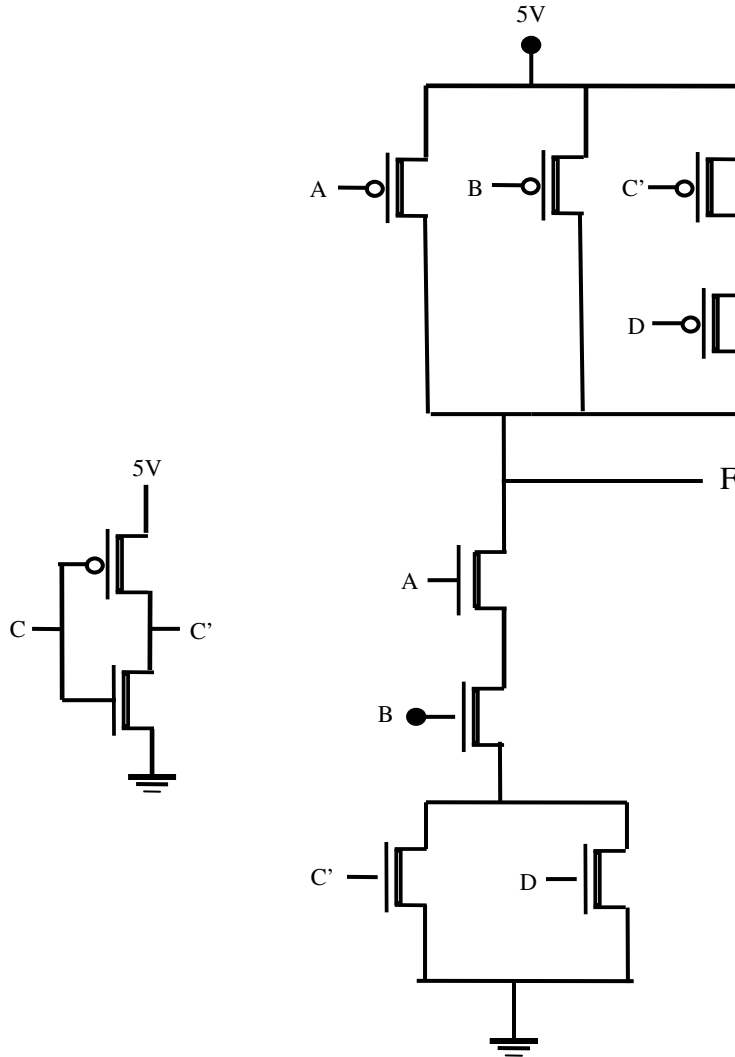
8-03-2006

Duration 110 minutes

Q1. (20 points)

Draw a circuit, using NMOS and PMOS transistors, which implements the function  
 $F = A' + B' + CD'$ . Complements of the input variables are not available.

Solution:  $F = A' + B' + CD' = [A \cdot B \cdot (C' + D)]'$



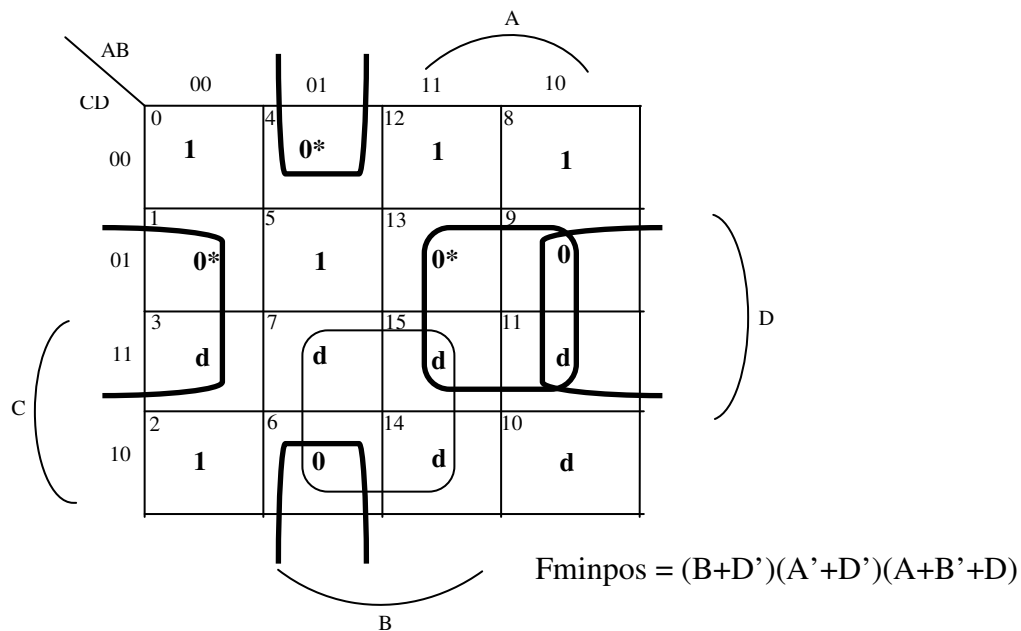
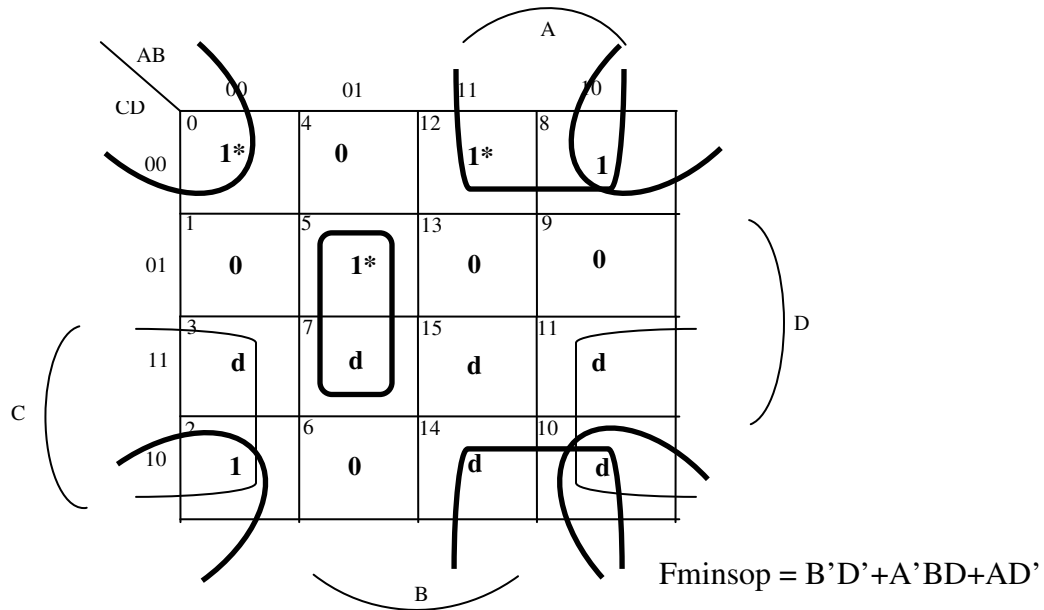
Q2. (20 points)

Find all minimal sums and all minimal products for

$$F = \sum_{A,B,C,D} (0, 2, 5, 8, 12) + d(3, 7, 10, 11, 14, 15).$$

Which of the solutions you have found are equivalent, why? Equivalent means having the same truth table.

Solution:



In finding Fminsop we have made the following assignments to the don't cares:

3	7	10	11	14	15
0	1	1	0	1	0

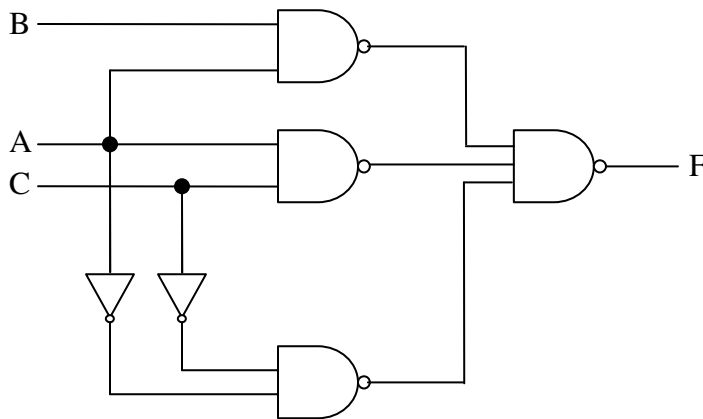
In finding Fminpos we have made the following assignments to the don't cares:

3	7	10	11	14	15
0	1	1	0	1	0

Thus in both cases the don't cares take the same values, and therefore the two solutions are equivalent.

Q3. (20 points)

Given the circuit below



- Find an expression for F.
- Write down the truth table of F given that the input combinations  $ABC = 000$ ,  $ABC = 011$ , and  $ABC = 111$  never occur.
- Find and draw a minimal 2-level NAND-NAND circuit which does the same job as the above drawn circuit for the input combinations which occur.

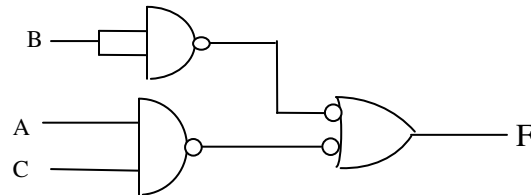
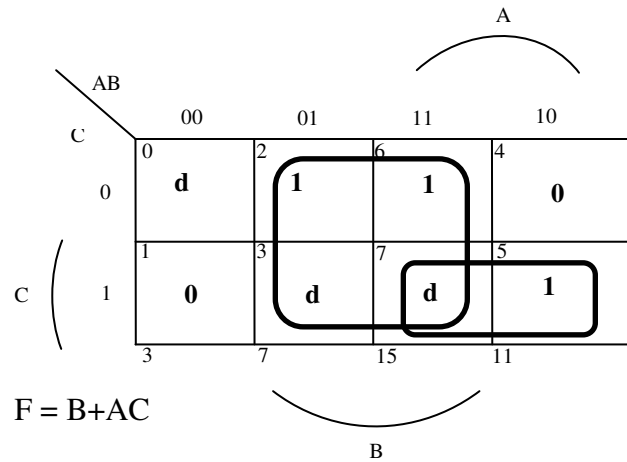
Solution:

a)  $F = [(AB)'(AC)'(A'C')]' = AB + AC + A'C'$

b)

A	B	C	F
0	0	0	d
0	0	1	0
0	1	0	1
0	1	1	d
1	0	0	0
1	0	1	1
1	1	0	1
1	1	1	d

c)



Q4. a) (10 points) The operator with symbol  $**$  is defined as  $A**B = A'B'$ . Is this operator commutative, why? Is this operator associative, why?

b) (10 points) The statement  $A \Rightarrow B$  (which reads as  $A$  implies  $B$ ) is a function of  $A$  and  $B$ , with the truth table

$A$	$B$	$A \Rightarrow B$
0	0	1
0	1	1
1	0	0
1	1	1

Consider the statement  $G: A \Rightarrow B + C$ , and also the statement  $H: AB' \Rightarrow C$ . Show that  $G=H$ .

Solution:

a)  $A**B = A'B' = B'A' = B**A$  Therefore  $**$  is commutative

$$A**(B**C) = A**(B'C') = A'(B'C')' = A'(B+C) = A'B + A'C$$

$$(A ** B) ** C = (A' B') ** C = (A' B')' C' = (A + B) C' = A C' + B C'$$

Thus  $A ** (B ** C) \neq (A ** B) ** C$  and  $**$  is not associative.

b)  $A \Rightarrow B \equiv A' + B$  from the truth table.

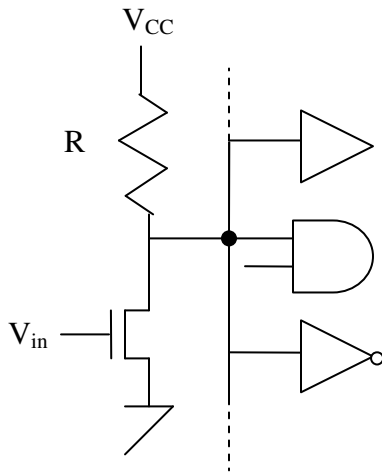
Therefore  $G : A \Rightarrow B + C \equiv A' + B + C$

and  $H : AB' \Rightarrow C \equiv (AB')' + C = A' + B + C$ .

Thus  $G = H$ .

Q5. (20 points)

An open drain NMOS transistor with pull up resistor R drives 10 various CMOS gates as shown below. The whole circuit operates from a supply of  $V_{CC} = 5V$ .



The CMOS family has the following specifications: For a supply of 5V

$V_{IHmin} = 3.5 V$  (Minimum voltage accepted as HIGH)

$V_{ILmax} = 1.5 V$  (Maximum voltage accepted as LOW)

$I_{ILmax} = -1 \mu A$  (Maximum input current for LOW input)

$I_{IHmax} = 1.5 \mu A$  (Maximum input current for HIGH input)

( Currents are defined as into the gate)

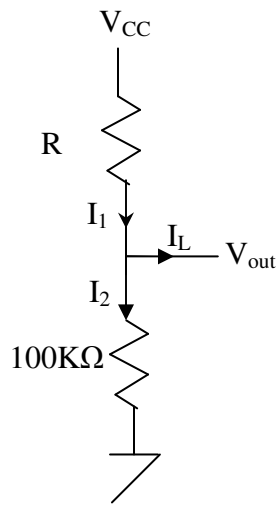
The ON and OFF resistances of the NMOS transistor are  $100\Omega$  and  $100K\Omega$  respectively.

a) Find the maximum value of R for a High Noise Margin of 0.5 volts.

b) Find the minimum value of R for a Low Noise Margin of 0.5 volts.

Solution:

a) Output High case:



$$I_L = 15\mu A$$

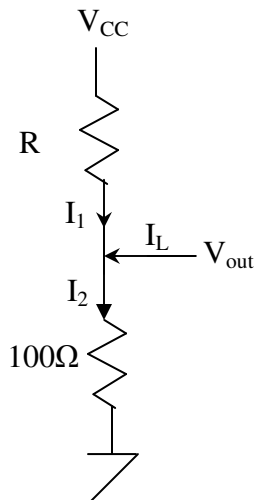
$$V_{out} = 4V$$

$$I_2 = \frac{4}{100K\Omega} = 40\mu A$$

$$I_1 = 15\mu A + 40\mu A = 55\mu A$$

$$R = \frac{5-1}{55\mu A} = 18.18K\Omega$$

b) Output Low case:



$$I_L = 10\mu A$$

$$V_{out} = 1V$$

$$I_2 = \frac{1}{100\Omega} = 10mA$$

$$I_1 = 10mA - 10\mu A \approx 10mA$$

$$R = \frac{5-1}{10mA} = 400\Omega$$